

2SK3309(Q)

2SK3309(Q) Information

Heisener.com	2SK3309(Q) Toshiba Semiconductor and Storage Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 450V 10A TO220FL TO-220-3, Short Tab For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



2SK3309(Q) Specifications

Manufacturer Part Number	2SK3309(Q)
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3, Short Tab
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	450V
Current - Continuous Drain (Id) @ 25°C	10A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	5V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	23nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	920pF @ 10V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	65W (Tc)
Rds On (Max) @ Id, Vgs	650 mOhm @ 5A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220FL
Package / Case	TO-220-3, Short Tab
	Report errors?

2SK3309(Q) Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE ELARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.



If you have any question about 2SK3309(Q), please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com